

## CORRECTION

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## Correction: Graphene oxide-based silsesquioxane-crosslinked networks – synthesis and rheological behavior

Mina Namvari,<sup>ab</sup> Lei Du<sup>ab</sup> and Florian J. Stadler<sup>\*a</sup>Correction for 'Graphene oxide-based silsesquioxane-crosslinked networks – synthesis and rheological behavior' by Mina Namvari *et al.*, *RSC Adv.*, 2017, **7**, 21531–21540, <https://doi.org/10.1039/C7RA02764H>.

The authors regret that the Raman data in Fig. 3 cannot be relied upon. They found after publishing the data that the background scatter compensation routine of the Raman measurement was omitted by the operator but that it does not affect the peaks that are used to prove the successful synthesis.

An independent expert has concluded that the other data does support the conclusions that the material has been synthesised. The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

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